

DOCKET NO: 242110US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
KEIJI HOSOTANI ET AL : EXAMINER: NOT YET ASSIGNED  
SERIAL NO: NEW APPLICATION :  
FILED: HEREWITH : GROUP ART UNIT: NOT YET ASSIGNED  
FOR: SEMICONDUCTOR MEMORY :  
DEVICE USING MAGNETO  
RESISTIVE ELEMENT AND  
METHOD OF MANUFACTURING  
THE SAME

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to an action on the merits, please amend the above-identified divisional application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 4 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.